

Vishay Siliconix

## 10 pA, Ultra Low Leakage and Quiescent Current, Load Switch with Reverse Blocking

### DESCRIPTION

The SiP32431 and SiP32432 are ultra low leakage and quiescent current slew rate controlled high side switches with reverse blocking capability. The switches are of a low on resistance p-channel MOSFET that supports continuous current up to 1.4 A.

The SiP32431 and SiP32432 operate with an input voltage from 1.5 V to 5.5 V.

The SiP32431 and SiP32432 feature low input logic level to interface with low control voltage from microprocessors. The SiP32431 is of logic high enable control, while SiP32432 is of logic low enable control. Both devices have a very low operating current, typically 10 pA at 3.3 V power supply.

The SiP32431 and SiP32432 are available in lead (Pb)-free package options including 6 pin SC-70-6, and 4 pin TDFN4 1.2 mm x 1.6 mm DFN4 packages. The operation temperature range is specified from -40  $^{\circ}$ C to +85  $^{\circ}$ C.

The SiP32431 and SiP32432 compact package options, operation voltage range, and low operating current make it a good fit for battery power applications.

### FEATURES

- 1.5 V to 5.5 V input voltage range
- No bias power rail required
  Low on-resistance R<sub>DS(on)</sub>,
- typically 105 m $\Omega$  at 5 V and 135 m $\Omega$  at 3 V for TDFN4 1.2 mm x 1.6 mm package
- Typical 147 m $\Omega$  at 5 V and 178 m $\Omega$  at 3 V for SC-70-6 package
- Slew rate controlled turn-on time: 100 μs
- Ultra low leakage and quiescent current:
- V<sub>IN</sub> quiescent current = 0.01 nA
- V<sub>IN</sub> shutdown leakage = 0.20 nA
- Reverse blocking capability
- SC-70-6 and TDFN4 1.2 mm x 1.6 mm packages
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## APPLICATIONS

- Wireless sensor network
- Smart meters
- Wearable
- Internet of things
- Portable medical devices
- Security systems
- Battery powered devices
- Portable Instruments

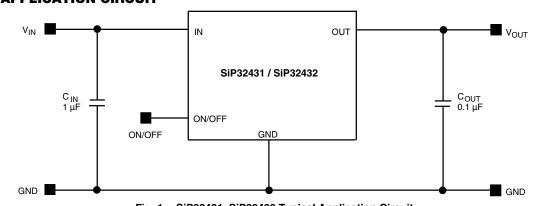


Fig. 1 - SiP32431, SiP32432 Typical Application Circuit

ORDERING INFORMATION								
PART NUMBER	MARKING	ENABLE	PACKAGE	TEMPERATURE RANGE				
SiP32431DR3-T1GE3	MAxx	High enable	SC-70-6					
SiP32432DR3-T1GE3	MDxx	Low enable	50-70-6	-40 °C to +85 °C				
SiP32431DNP3-T1GE4	Dx	High enable	TDFN4 1.2 mm x 1.6 mm	-40 C to +85 C				
SiP32432DNP3-T1GE4	Vx	Low enable						

Notes

x = lot code

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1 For technical questions, contact: <u>powerictechsupport@vishay.com</u> Document Number: 66597

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**TYPICAL APPLICATION CIRCUIT** 



RoHS

HALOGEN

FREE



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-GE3 denotes halogen-free and RoHS-compliant

Please use the SiP32431DR3-T1GE3 to replace SiP32431DR3-T1-E3

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		LIMIT	UNIT			
Supply input voltage (VIN)		-0.3 to +6				
Enable input voltage (V <sub>ON/OFF</sub> )		-0.3 to +6	V			
Output voltage (V <sub>OUT</sub> )		-0.3 to +6				
Maximum continuous switch current (I <sub>max</sub> )	SC-70-6 package	1.2				
Maximum continuous switch current (I <sub>max.)</sub>	TDFN4 1.2 mm x 1.6 mm	1.4	•			
Maximum pulsed current (I <sub>DM</sub> ) V <sub>IN</sub>	$V_{IN} \ge 2.5 \text{ V}$	3	— A			
(pulsed at 1 ms, 10 % duty cycle)	V <sub>IN</sub> < 2.5 V	1.6				
ESD rating (HBM)		4000	V			
Junction temperature (T <sub>J</sub> )		-40 to +125	°C			
Thermal register $a_{0}$ (0)	6 pin SC-70-6 <sup>b</sup>	220	*CAN			
Thermal resistance ( $\theta_{JA}$ ) <sup>a</sup>	4 pin TDFN4 1.2 mm x 1.6 mm <sup>c</sup>	170	°C/W			
Devues discipation (D.) 8	6 pin SC-70- 6 <sup>b</sup>	250				
Power dissipation (P <sub>D</sub> ) <sup>a</sup>	4 pin TDFN4 1.2 mm x 1.6 mm <sup>c</sup>	324	— mW			

#### Notes

a. Device mounted with all leads and power pad soldered or welded to PC board

b. Derate 4.5 mW/°C above  $T_A = 70$  °C

c. Derate 5.9 mW/°C above T<sub>A</sub> = 70 °C, see PCB layout

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating / conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING RANGE					
PARAMETER	LIMIT	UNIT			
Input voltage range (V <sub>IN</sub> )	1.5 to 5.5	V			
Operating temperature range	-40 to +85	°C			

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SPECIFICATIONS							
PARAMETER	SYMBOL				<b>LIMITS</b> -40 °C to +85 °C		
		(Typical values are at $T_A = 25$	(Typical values are at $T_A = 25$ °C)			MAX. <sup>a</sup>	
Operating voltage <sup>c</sup>	V <sub>IN</sub>			1.5	-	5.5	V
Quiescent current		$V_{IN} = 3.3 \text{ V}, \text{ V}_{on/off} = 3.3 \text{ V}$		-	0.01	100	
Quiescent current	Ι <sub>Q</sub>	$V_{IN} = 5 V, V_{on/off} = 5 V$		-	0.05	1000	
Off supply current	las a	$V_{IN} = 3.3 \text{ V}, V_{on/off} = 0 \text{ V}, \text{OUT} = 0$	open	-	0.01	100	
On supply current	I <sub>Q(off)</sub>	$V_{IN} = 5 V, V_{on/off} = 0 V, OUT = 0$	pen	-	-	1000	nA
Off switch current		$V_{IN} = 3.3 \text{ V}, V_{on/off} = 0 \text{ V}, \text{OUT} =$	1 V	-	0.2	100	
On switch current	I <sub>SD(off)</sub>	$V_{IN} = 5 \text{ V}, V_{on/off} = 0 \text{ V}, \text{ OUT} = 0 \text{ V}$		-	-	1000	
Reverse blocking current	I <sub>RB</sub>	$V_{OUT} = 5.5 \text{ V}, V_{IN} = 0, V_{on/off} = ina$	active	-	130	1000	
	R <sub>DS(on)</sub>	$V_{\rm IN} = 5 V I_{\rm I} = 500 \text{ mA} T_{\rm A} = 25 ^{\circ}\text{C}$	SC-70-6	-	147	230	
			TDFN4	-	105	200	
		$V_{\text{IN}}$ = 4.2 V, $I_{\text{L}}$ = 500 mA, $T_{\text{A}}$ = 25 °C	SC-70-6	-	155	250	mΩ
			TDFN4	-	110		
On-resistance		V <sub>IN</sub> = 3 V, I <sub>L</sub> = 500 mA, T <sub>A</sub> = 25 °C	SC-70-6	-	178	290 480	
			TDFN4	-	135		
			SC-70-6	-	275		
			TDFN4 SC-70-6	-	230 395		
		$V_{IN}$ = 1.5 V, $I_L$ = 500 mA, $T_A$ = 25 °C	= 25 °C TDFN4		395	520	
On-resistance tempcoefficient	TD <sub>RDS</sub>			-	2800	-	ppm/°C
	· - ND3	$V_{IN} \ge 1.5 \text{ V to} < 1.8 \text{ V}$		-	-	0.3	pp, e
On / off input low voltage <sup>c</sup>	VIL	$V_{\rm IN} \ge 1.8 \text{ V to } < 2.7 \text{ V}$		-	-	0.4	-
	12	$V_{IN} \ge 2.7 \text{ V to} \le 5.5 \text{ V}$		-	-	0.6	-
		$V_{IN} \ge 1.5 \text{ V to} < 2.7 \text{ V}$		1.3	-	-	V
On / off input low voltage c	VIH	$V_{IN} \ge 2.7 \text{ V to} < 4.2 \text{ V}$		1.5	-		
		$V_{\rm IN} \ge 2.2 \text{ V to} \le 5.5 \text{ V}$		1.8	-	-	
		$V_{on/off} = 3.3 V$		-	0.014	100	
On / off input leakage	I <sub>ON/OFF</sub>	V <sub>on/off</sub> = 5.5 V		-	0.042	1000	nA
Output turn-on delay time	t <sub>d(on)</sub>			-	20	40	
Output turn-on rise time	t <sub>(on)</sub>	$V_{IN} = 5 V$ , $R_{load} = 10 \Omega$ , $T_A = 25$	°C	-	140	180	μs
Output turn-off delay time	t <sub>d(off)</sub>			-	4	10	

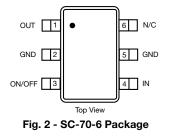
#### Notes

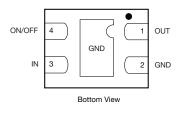
a. The algebriac convention whereby the most negative value is a minimum and the most positive a maximum

b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing

c. For  $V_{IN}$  outside this range consult typical on / off threshold curve

### **PIN CONFIGURATION**





#### Fig. 3 - TDFN4 1.2 mm x 1.6 mm Package

PIN DES	CRIPTION	I	
PIN NU	IMBER	NAME	FUNCTION
SC-70-6	TDFN4		FONCTION
4	3	IN	This pin is the p-channel MOSFET source connection. Bypass to ground through a 1 $\mu F$ capacitor

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PIN DES	PIN DESCRIPTION					
PIN NUMBER NAME		NAME	FUNCTION			
SC-70-6	TDFN4		FUNCTION			
2, 5	2	GND	Ground connection			
3	4	ON / OFF	Enable input			
1	1	OUT	This pin is the p-channel MOSFET drain connection. Bypass to ground through a 0.1 $\mu$ F capacitor			

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## TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

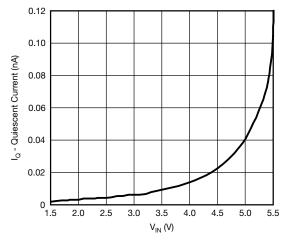


Fig. 4 - Quiescent Current vs. Input Voltage

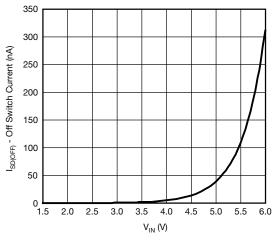


Fig. 5 - Off Switch Current vs. Input Voltage

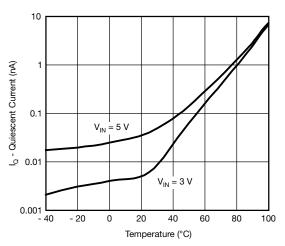


Fig. 6 - Quiescent Current vs. Temperature

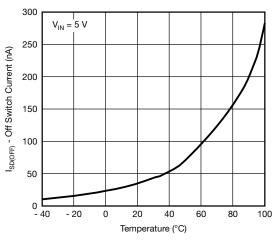
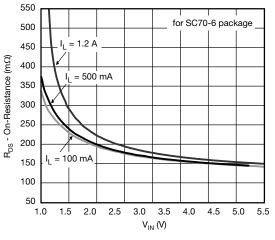
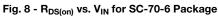


Fig. 7 - Off Switch Current vs. Temperature





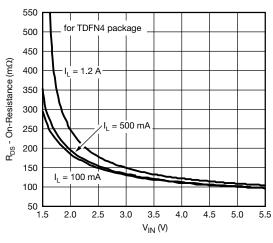


Fig. 9 - R<sub>DS(on)</sub> vs. Input Voltage

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## TYPICAL CHARACTERISTICS (internally regulated, 25 °C, unless otherwise noted)

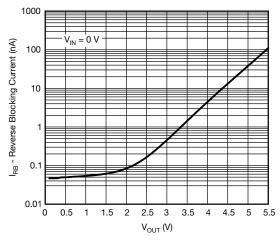
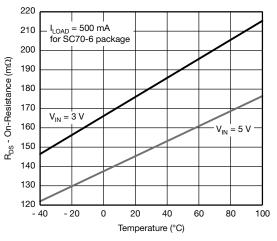
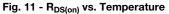


Fig. 10 - Reverse Blocking Current vs. VOUT





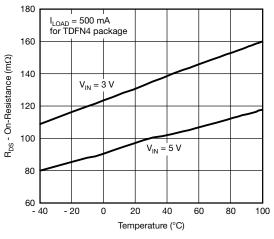


Fig. 12 - R<sub>DS(on)</sub> vs. Temperature

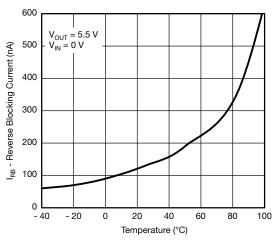
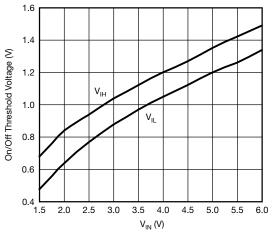
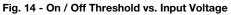
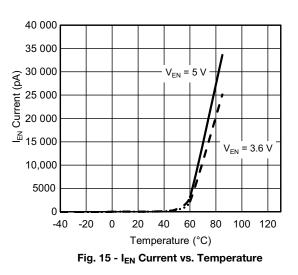


Fig. 13 - Reverse Blocking Current vs. Temperature







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## **TYPICAL WAVEFORMS**

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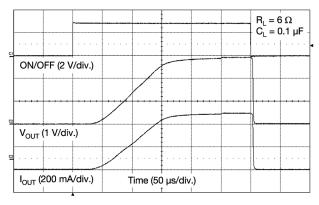


Fig. 16 - Switching (V<sub>IN</sub> = 3 V)

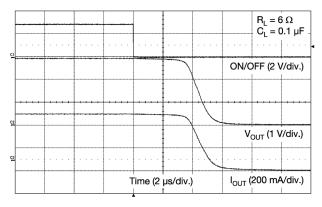
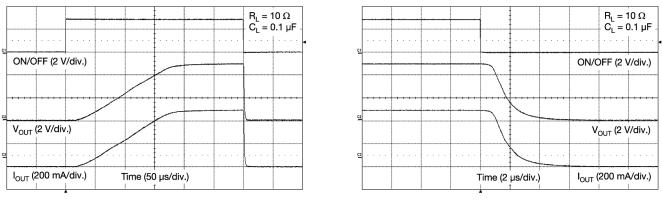


Fig. 18 - Turn-Off (V<sub>IN</sub> = 3 V)







### **BLOCK DIAGRAM**

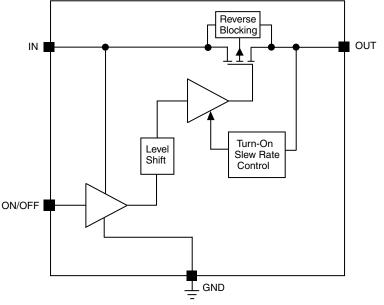


Fig. 20 - Functional Block Diagram

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# SiP32431DN, SiP32431DR, SiP32432DN, SiP32432DR

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## PCB LAYOUT

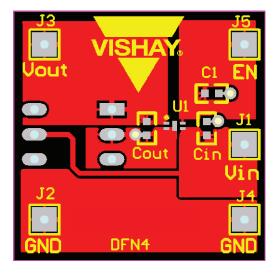


Fig. 21 - Top, TDFN4 1.2 mm x 1.6 mm PCB Layout

### **DETAILED DESCRIPTION**

The SiP32431 and SiP32432 are p-channel MOSFET power switches designed for high-side slew rate controlled load-switching applications. Once turned on, the slew-rate control circuitry is activated and current is ramped in a linear fashion until it reaches the level required for the output load condition. This is accomplished by first elevating the gate voltage of the MOSFET up to its threshold voltage and then by linearly increasing the gate voltage until the MOSFET becomes fully enhanced. At this point, the gate voltage is then quickly increased to the full input voltage to reduce  $R_{DS(on)}$  of the MOSFET switch and minimize any associated power losses.

### **APPLICATION INFORMATION**

### Input Capacitor

While a bypass capacitor on the input is not required, a 1  $\mu$ F or larger capacitor for C<sub>IN</sub> is recommended in almost all applications. The bypass capacitor should be placed as physically close as possible to the input pin to be effective in minimizing transients on the input. Ceramic capacitors are recommended over tantalum because of their ability to withstand input current surges from low impedance sources such as batteries in portable devices.

### **Output Capacitor**

A 0.1  $\mu$ F capacitor or larger across V<sub>OUT</sub> and GND is recommended to insure proper slew operation. C<sub>OUT</sub> may be increased without limit to accommodate any load transient condition with only minimal affect on the SiP32431 and SiP32432 turn on slew rate time. There are no ESR or capacitor type requirement.

### Enable

The on / off pin is compatible with both TTL and CMOS logic voltage levels.

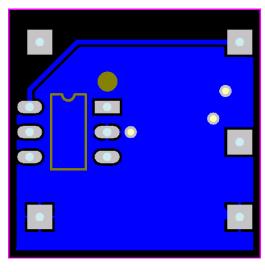


Fig. 22 - Bottom, TDFN4 1.2 mm x 1.6 mm PCB Layout

### Protection Against Reverse Voltage Condition

The SiP32431 and SiP32432 contain a body snatcher that normally connects the body to the source (IN) when the device is enabled. In case where the device is disabled but the  $V_{OUT}$  is higher than the  $V_{IN}$ , the n-type body is switched to out, reverse bias the body diode to prevent the current from going back to the input.

#### Thermal Considerations

The physical limitations of the layout and assembly of the device limit the maximum current levels as stated in the Absolute Maximum Ratings table. However, another limiting characteristic for the safe operating load current is the thermal power dissipation of the package. To obtain the highest power dissipation, the power pad of the TDFN4 package should be connected to a heat sink on the printed circuit board.

The maximum power dissipation in any application is dependent on the maximum junction temperature,  $T_{J (max.)} = 125 \text{ °C}$ , the junction-to-ambient thermal resistance for the TDFN4 1.2 mm x 1.6 mm package,  $\theta_{J-A} = 170 \text{ °C/W}$ , and the ambient temperature,  $T_A$ , which may be formulaically expressed as:

P (max.) = 
$$\frac{T_{J (max.)} - T_{A}}{\theta_{J-A}} = \frac{125 - T_{A}}{170}$$

It then follows that, assuming an ambient temperature of 70 °C, the maximum power dissipation will be limited to about 324 mW.

So long as the load current is below the absolute maximum limits, the maximum continuous switch current becomes a function two things: the package power dissipation and the  $R_{DS(on)}$  at the ambient temperature.

As an example let us calculate the worst case maximum load current at T\_A = 70 °C. The worst case  $R_{DS(on)}$  at 25 °C

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occurs at an input voltage of 1.5 V and is equal to 520 m $\Omega$ . The R<sub>DS(on)</sub> at 70 °C can be extrapolated from this data using the following formula

 $R_{DS(on)}$  (at 70 °C) =  $R_{DS(on)}$  (at 25 °C) x (1 +  $T_C x \Delta T$ )

Where T<sub>C</sub> is 3300 ppm/°C. Continuing with the calculation we have

R<sub>DS(on)</sub> (at 70 °C) = 520 mΩ x (1 + 0.0033 x (70 °C - 25 °C)) =  $597 \text{ m}\Omega$ 

The maximum current limit is then determined by

$$I_{LOAD (max.)} < \sqrt{\frac{P (max.)}{R_{DS(on)}}}$$

which in case is 0.74 A. Under the stated input voltage condition, if the 0.74 A current limit is exceeded the internal die temperature will rise and eventually, possibly damage the device.



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PRODUCT SUMMARY				
Part number	SiP32431DN	SiP32431DR	SiP32432DN	SiP32432DR
Description	$\begin{array}{c} 1.5 \text{ V to } 5.5 \text{ V, } 105 \\ \text{m}\Omega \text{, } 10 \text{ pA } \text{I}_{\text{Q}}\text{,} \\ \text{bidirectional off} \\ \text{isolation, EN active} \\ \text{high} \end{array}$	1.5 V to 5.5 V, 147 mΩ, 10 pA I <sub>Q</sub> , bidirectional off isolation, EN active high	$\begin{array}{c} 1.5 \text{ V to } 5.5 \text{ V, } 105 \\ \text{m}\Omega, \ 10 \text{ pA } \text{I}_{\text{Q}}, \\ \text{bidirectional off} \\ \text{isolation, EN active} \\ \text{low} \end{array}$	$\begin{array}{c} 1.5 \text{ V to } 5.5 \text{ V, } 147 \\ \text{m}\Omega \text{, } 10 \text{ pA } \text{I}_{\text{Q}}\text{,} \\ \text{bidirectional off} \\ \text{isolation, EN active} \\ \text{low} \end{array}$
Configuration	Single	Single	Single	Single
Slew rate time (µs)	140	140	140	140
On delay time (µs)	20	20	20	20
Input voltage min. (V)	1.5	1.5	1.5	1.5
Input voltage max. (V)	5.5	5.5	5.5	5.5
On-resistance at input voltage min. (m $\Omega$ )	350	395	350	395
On-resistance at input voltage max. (m $\Omega$ )	105	147	105	147
Quiescent current at input voltage min. (µA)	0.000002	0.000002	0.000002	0.000002
Quiescent current at input voltage max. (µA)	0.00004	0.00004	0.00004	0.00004
Output discharge (yes / no)	No	No	No	No
Reverse blocking (yes / no)	Yes	Yes	Yes	Yes
Continuous current (A)	1.4	1.4	1.4	1.4
Package type	TDFN4	SC-70-6	TDFN4	SC-70-6
Package size (W, L, H) (mm)	1.2 x 1.6 x 0.5	2.0 x 2.0 x 0.5	1.2 x 1.6 x 0.5	2.0 x 2.0 x 0.5
Status code	2	2	2	2
Product type	Slew rate	Slew rate	Slew rate	Slew rate
Applications	Computers, consumer, industrial, healthcare, networking, portable	Computers, consumer, industrial, healthcare, networking, portable	Computers, consumer, industrial, healthcare, networking, portable	Computers, consumer, industrial, healthcare, networking, portable

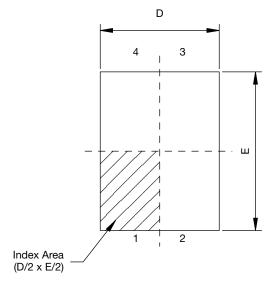
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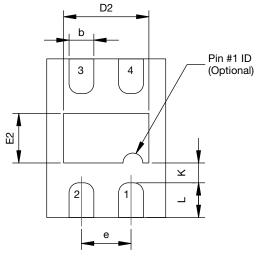


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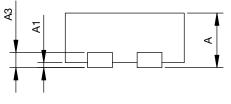
TDFN4 1.2 x 1.6 Case Outline



Top View



Bottom View



Side View

DIM.		MILLIMETERS		INCHES			
DINI.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	0.45	0.55	0.60	0.017	0.022	0.024	
A1	0.00	-	0.05	0.00	-	0.002	
A3	0.	15 REF. or 0.127 REF	. (1)		0.006 or 0.005 <sup>(1)</sup>		
b	0.20	0.25	0.30	0.008	0.010	0.012	
D	1.15	1.20	1.25	0.045	0.047	0.049	
D2	0.81	0.86	0.91	0.032	0.034	0.036	
е		0.50 BSC		0.020			
E	1.55	1.60	1.65	0.061	0.063	0.065	
E2	0.45	0.50	0.55	0.018	0.020	0.022	
К		0.25 typ.			0.010 typ.		
L	0.25	0.30	0.35	0.010	0.012	0.014	
L ECN: T16-0143-F DWG: 5995	0.25 Rev. C, 18-Apr-16	0.30	0.35	0.010	0.012	0.0	

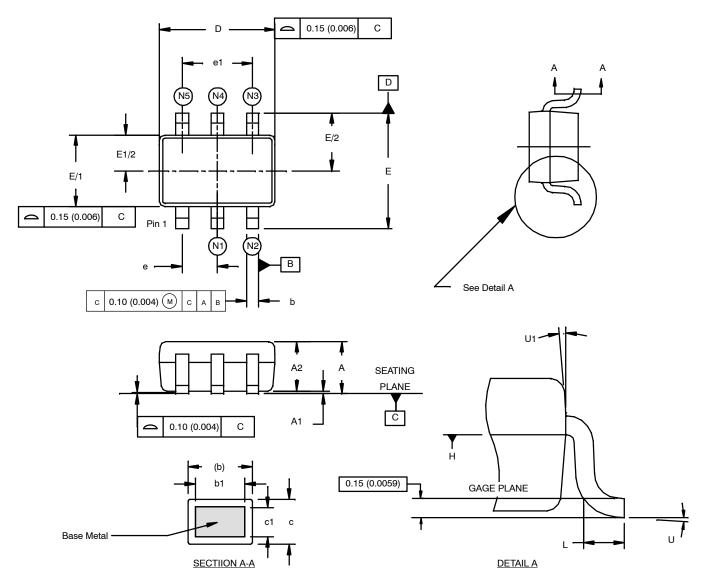
#### Note

<sup>(1)</sup> The dimension depends on the leadframe that assembly house used.

1



## SC-70: 3/4/5/6-LEADS (PIC ONLY)



Pin	LEAD COUNT					
Code	3	4	5	6		
N1	-	-	2	2		
N2	2	2	3	3		
N3	-	3	4	4		
N4	3	-	-	5		
N5	-	4	5	6		

#### NOTES:

- 1. Dimensioning and tolerancing per ANSI Y14.5M-1994.
- 2. Controlling dimensions: millimeters converted to inch dimensions are not necessarily exact.
- Dimension "D" does not include mold flash, protrusion or gate burr. Mold flash, protrusion or gate burr shall not exceed 0.15 mm (0.006 inch) per side.
- 4. The package top shall be smaller than the package bottom. Dimension "D" and "E1" are determined at the outer most extremes of the plastic body exclusive of mold flash, tie bar burrs, gate burrs and interlead flash, but including any mismatch between the top and bottom of the plastic body.

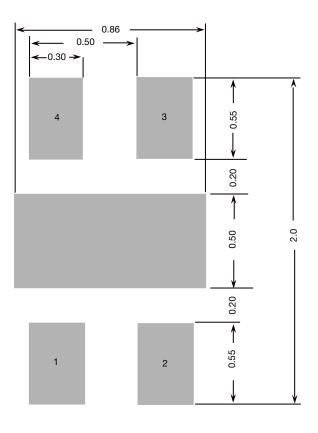


	Μ	ILLIMETE	INCHES			
Dim	Min	Nom	Max	Min	Nom	Max
Α	0.80	-	1.10	0.031	-	0.043
A1	0.00	-	0.10	0.000	-	0.004
A2	0.80	0.90	1.00	0.031	0.035	0.040
b	0.15	-	0.30	0.006	-	0.012
b1	0.15	0.20	0.25	0.006	0.008	0.010
С	0.08	-	0.25	0.003	-	0.010
c1	0.08	0.13	0.20	0.003	0.005	0.008
D	1.90	2.10	2.15	0.074	0.082	0.084
Е	2.00	2.10	2.20	0.078	0.082	0.086
E <sub>1</sub>	1.15	1.25	1.35	0.045	0.050	0.055
е		0.65 BSC			0.0255 BSC	
e <sub>1</sub>		1.30 BSC			0.0512 BSC	
L	0.26	0.36	0.46	0.010	0.014	0.018
U	0°	-	8°	0°	-	<b>8</b> °
U1	4°		10°	4°		10°



Vishay Siliconix

### **RECOMMENDED MINIMUM PADS FOR TDFN4 1.2 x 1.6**



Recommended Minimum Pads Dimensions in mm



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